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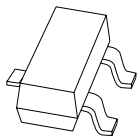
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Kind regards,

Team Nexperia



PBHV9040T

500 V, 0.25 A PNP high-voltage low V_{CEsat} (BISS) transistor

Rev. 02 — 15 January 2009

Product data sheet

1. Product profile

1.1 General description

PNP high-voltage low V_{CEsat} Breakthrough In Small Signal (BISS) transistor in a SOT23 (TO-236AB) small Surface-Mounted Device (SMD) plastic package.

NPN complement: PBHV8540T.

1.2 Features

- High voltage
- Low collector-emitter saturation voltage V_{CEsat}
- High collector current capability I_C and I_{CM}
- High collector current gain (h_{FE}) at high I_C
- AEC-Q101 qualified

1.3 Applications

- Electronic ballast for fluorescent lighting
- LED driver for LED chain module
- LCD backlighting
- High Intensity Discharge (HID) front lighting
- Automotive motor management
- Hook switch for wired telecom
- Switch mode power supply

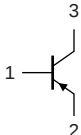
1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{CESM}	collector-emitter peak voltage	$V_{BE} = 0\text{ V}$	-	-	-500	V
V_{CEO}	collector-emitter voltage	open base	-	-	-400	V
I_C	collector current		-	-	-0.25	A
h_{FE}	DC current gain	$V_{CE} = -10\text{ V};$ $I_C = -50\text{ mA}$	100	200	-	

2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	base		 <i>sym013</i>
2	emitter		
3	collector		

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PBHV9040T	-	plastic surface-mounted package; 3 leads	SOT23

4. Marking

Table 4. Marking codes

Type number	Marking code ^[1]
PBHV9040T	W5*

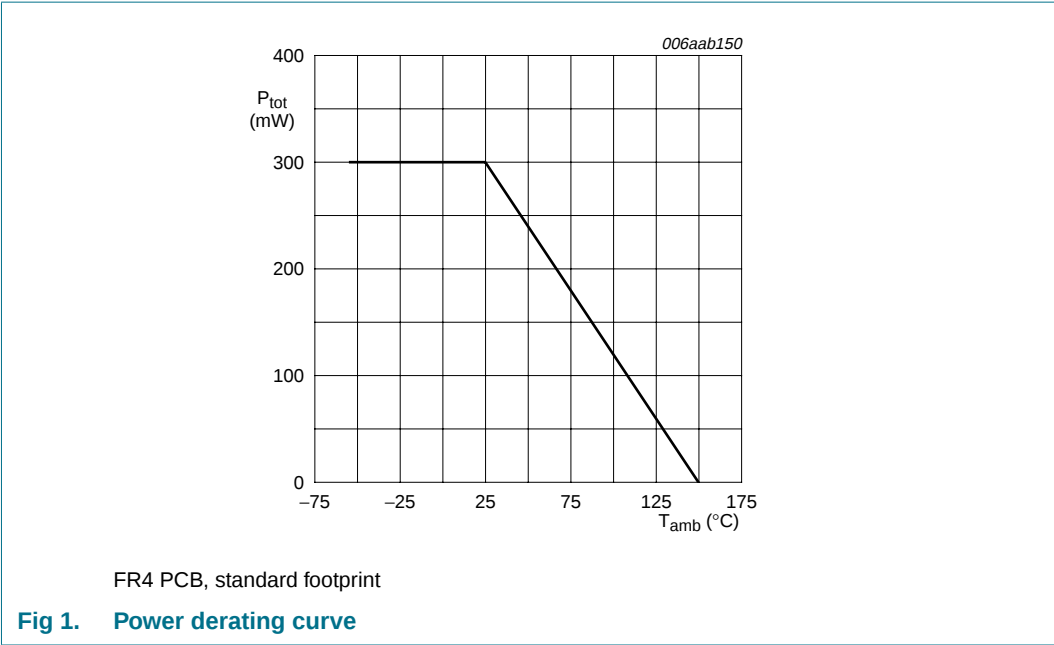
- [1] * = -: made in Hong Kong
* = p: made in Hong Kong
* = t: made in Malaysia
* = W: made in China

5. Limiting values

Table 5. Limiting values
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter	-	-500	V
V_{CEO}	collector-emitter voltage	open base	-	-400	V
V_{CESM}	collector-emitter peak voltage	$V_{BE} = 0\text{ V}$	-	-500	V
V_{EBO}	emitter-base voltage	open collector	-	-6	V
I_C	collector current		-	-0.25	A
I_{CM}	peak collector current	single pulse; $t_p \leq 1\text{ ms}$	-	-0.5	A
I_{BM}	peak base current	single pulse; $t_p \leq 1\text{ ms}$	-	-200	mA
P_{tot}	total power dissipation	$T_{amb} \leq 25\text{ }^{\circ}\text{C}$	[1]	300	mW
T_j	junction temperature		-	150	$^{\circ}\text{C}$
T_{amb}	ambient temperature		-55	+150	$^{\circ}\text{C}$
T_{stg}	storage temperature		-65	+150	$^{\circ}\text{C}$

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

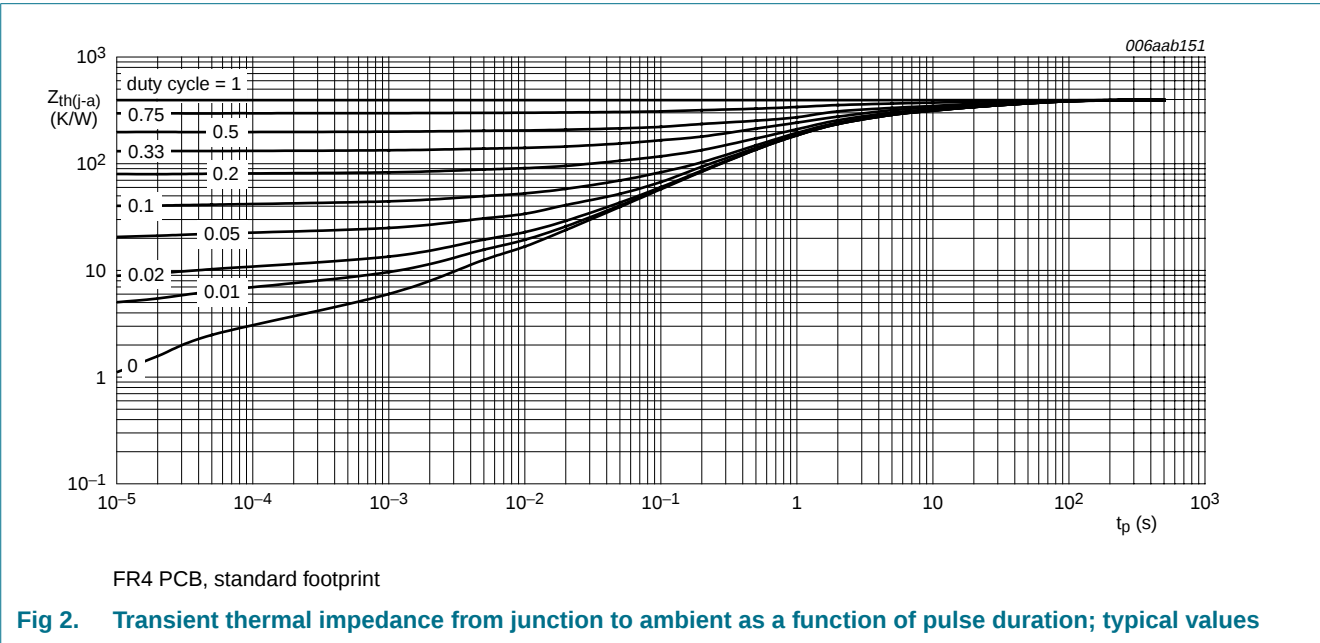


6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	417	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point		-	-	70	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.



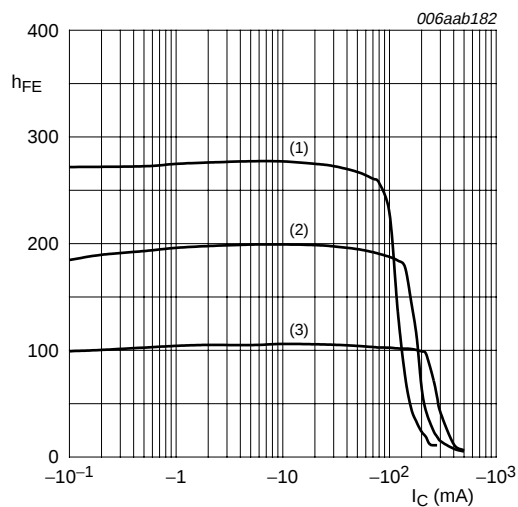
7. Characteristics

Table 7. Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified.

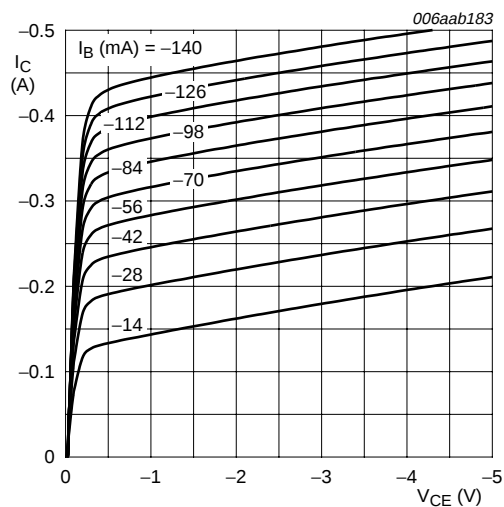
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I_{CBO}	collector-base cut-off current	$V_{CB} = -320\text{ V}; I_E = 0\text{ A}$	-	-	-100	nA
		$V_{CB} = -320\text{ V}; I_E = 0\text{ A}; T_j = 150\text{ }^{\circ}\text{C}$	-	-	-10	μA
I_{CES}	collector-emitter cut-off current	$V_{CE} = -320\text{ V}; V_{BE} = 0\text{ V}$	-	-	-100	nA
I_{EBO}	emitter-base cut-off current	$V_{EB} = -4\text{ V}; I_C = 0\text{ A}$	-	-	-100	nA
h_{FE}	DC current gain	$V_{CE} = -10\text{ V}$				
		$I_C = -50\text{ mA}$	100	200	-	
		$I_C = -100\text{ mA}$	80	200	-	
		$I_C = -250\text{ mA}$	[1] 10	25	-	
V_{CEsat}	collector-emitter saturation voltage	$I_C = -100\text{ mA}; I_B = -20\text{ mA}$	-	-110	-200	mV
V_{BEsat}	base-emitter saturation voltage	$I_C = -100\text{ mA}; I_B = -20\text{ mA}$	[1] -	-1	-1.1	V
f_T	transition frequency	$V_{CE} = -10\text{ V}; I_E = -10\text{ mA}; f = 100\text{ MHz}$	-	55	-	MHz
C_c	collector capacitance	$V_{CB} = -20\text{ V}; I_E = i_e = 0\text{ A}; f = 1\text{ MHz}$	-	7	-	pF
C_e	emitter capacitance	$V_{EB} = -0.5\text{ V}; I_C = i_c = 0\text{ A}; f = 1\text{ MHz}$	-	150	-	pF
t_d	delay time	$V_{CC} = -2\text{ V}; I_C = -0.15\text{ A};$	-	9	-	ns
t_r	rise time	$I_{Bon} = -0.03\text{ A};$	-	1810	-	ns
t_{on}	turn-on time	$I_{Boff} = 0.03\text{ A}$	-	1819	-	ns
t_s	storage time		-	715	-	ns
t_f	fall time		-	1085	-	ns
t_{off}	turn-off time		-	1800	-	ns

[1] Pulse test: $t_p \leq 300\text{ }\mu\text{s}; \delta \leq 0.02$.



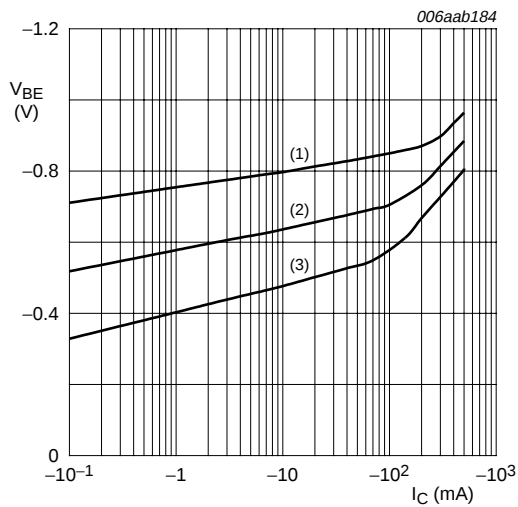
$V_{CE} = -10\text{ V}$
(1) $T_{amb} = 100^\circ C$
(2) $T_{amb} = 25^\circ C$
(3) $T_{amb} = -55^\circ C$

Fig 3. DC current gain as a function of collector current; typical values



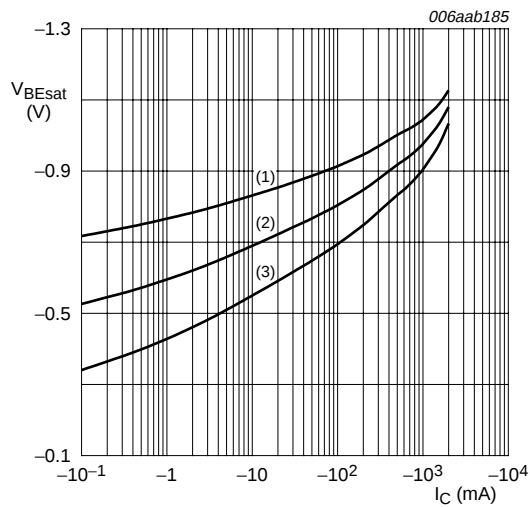
$T_{amb} = 25^\circ C$

Fig 4. Collector current as a function of collector-emitter voltage; typical values



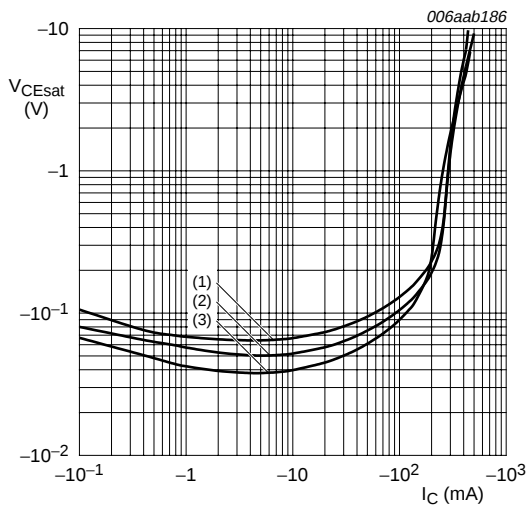
$V_{CE} = -10\text{ V}$
(1) $T_{amb} = -55^\circ C$
(2) $T_{amb} = 25^\circ C$
(3) $T_{amb} = 100^\circ C$

Fig 5. Base-emitter voltage as a function of collector current; typical values



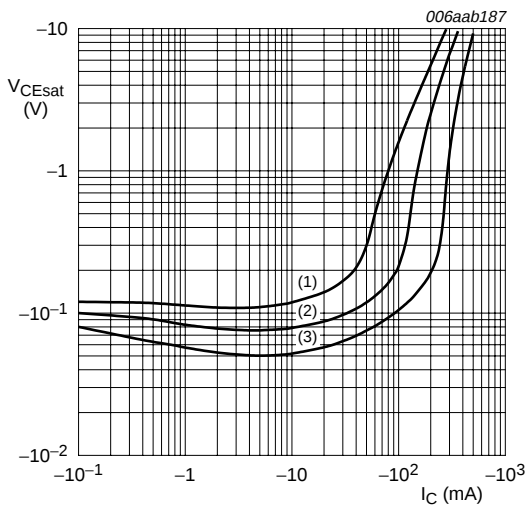
$I_C/I_B = 5$
(1) $T_{amb} = -55^\circ C$
(2) $T_{amb} = 25^\circ C$
(3) $T_{amb} = 100^\circ C$

Fig 6. Base-emitter saturation voltage as a function of collector current; typical values



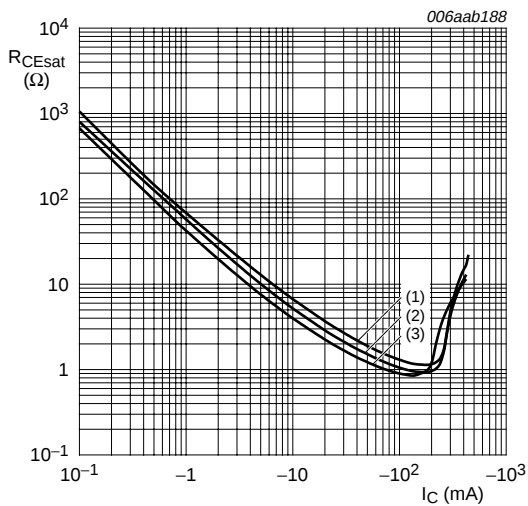
- $I_C/I_B = 5$
- (1) $T_{amb} = 100\text{ }^{\circ}\text{C}$
 - (2) $T_{amb} = 25\text{ }^{\circ}\text{C}$
 - (3) $T_{amb} = -55\text{ }^{\circ}\text{C}$

Fig 7. Collector-emitter saturation voltage as a function of collector current; typical values



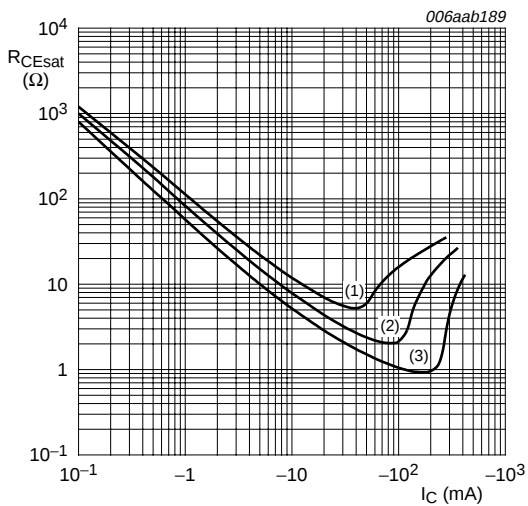
- $T_{amb} = 25\text{ }^{\circ}\text{C}$
- (1) $I_C/I_B = 20$
 - (2) $I_C/I_B = 10$
 - (3) $I_C/I_B = 5$

Fig 8. Collector-emitter saturation voltage as a function of collector current; typical values



- $I_C/I_B = 5$
- (1) $T_{amb} = 100\text{ }^{\circ}\text{C}$
 - (2) $T_{amb} = 25\text{ }^{\circ}\text{C}$
 - (3) $T_{amb} = -55\text{ }^{\circ}\text{C}$

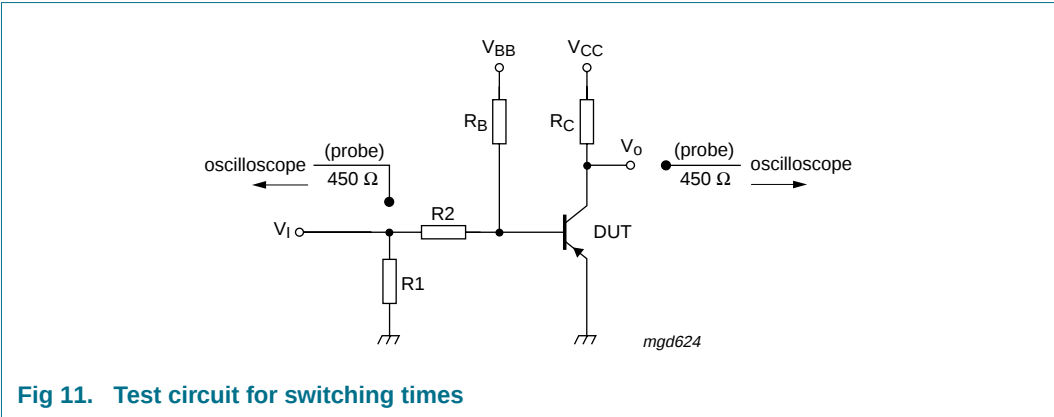
Fig 9. Collector-emitter saturation resistance as a function of collector current; typical values



- $T_{amb} = 25\text{ }^{\circ}\text{C}$
- (1) $I_C/I_B = 20$
 - (2) $I_C/I_B = 10$
 - (3) $I_C/I_B = 5$

Fig 10. Collector-emitter saturation resistance as a function of collector current; typical values

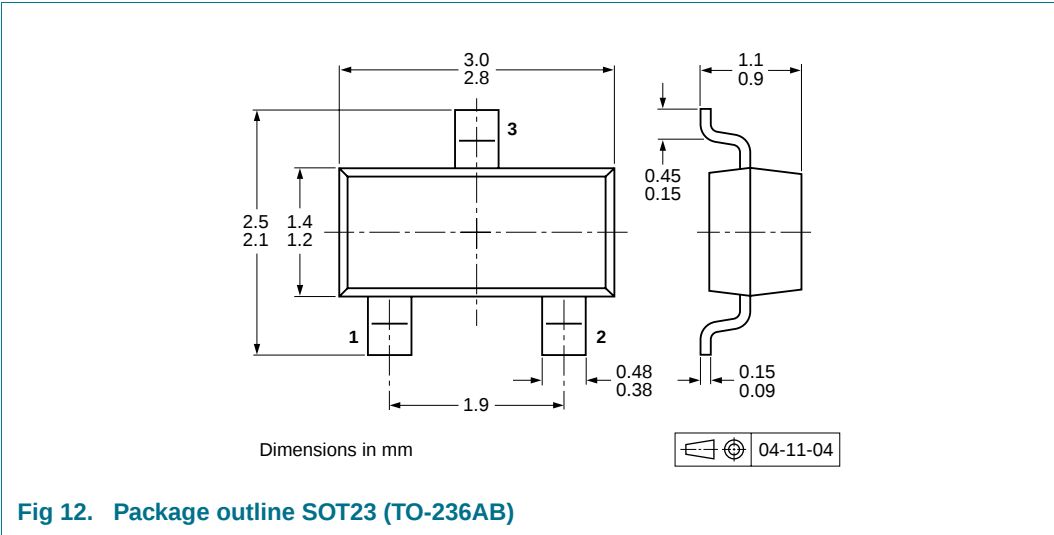
8. Test information



8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

9. Package outline



10. Packing information

Table 8. Packing methods
The indicated -xxx are the last three digits of the 12NC ordering code.[\[1\]](#)

Type number	Package	Description	Packing quantity	
			3000	10000
PBHV9040T	SOT23	4 mm pitch, 8 mm tape and reel	-215	-235

[1] For further information and the availability of packing methods, see [Section 14](#).

11. Soldering

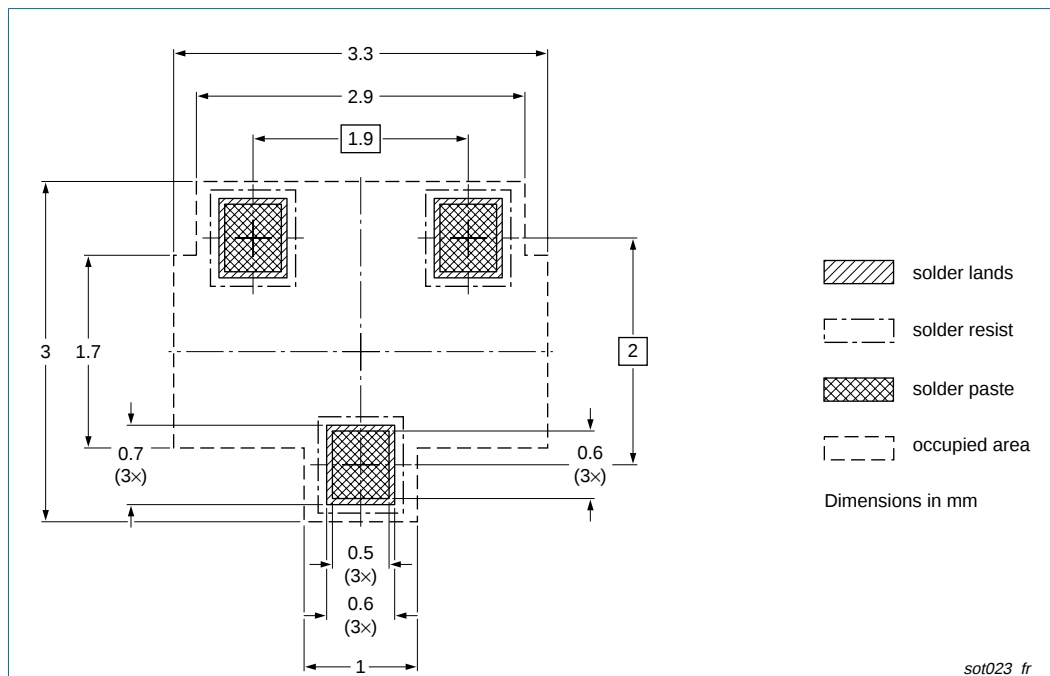


Fig 13. Reflow soldering footprint SOT23 (TO-236AB)

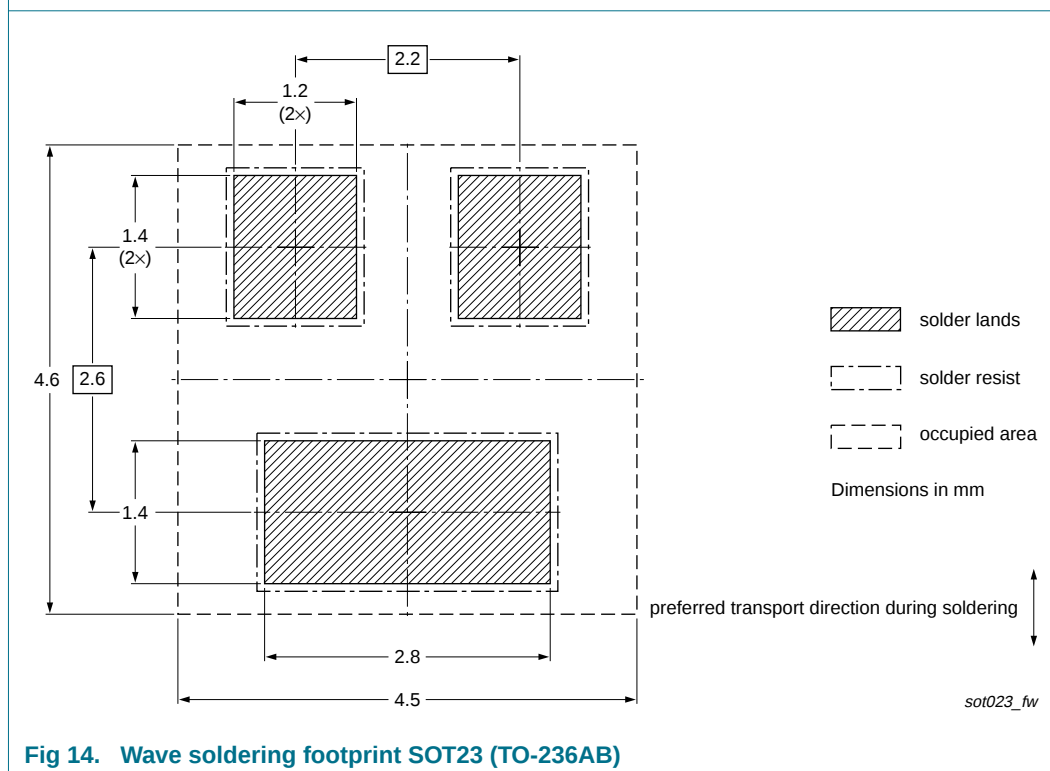


Fig 14. Wave soldering footprint SOT23 (TO-236AB)

12. Revision history

Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PBHV9040T_2	20090115	Product data sheet	-	PBHV9040T_1
Modifications:	• Table 5: I_{BM} value changed from –100 mA to –200 mA • Table 7: t_{off} value amended to 1800 ns • Section 13 "Legal information": updated			
PBHV9040T_1	20080212	Product data sheet	-	-

13. Legal information

13.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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